



# DDA (LO-R1) H

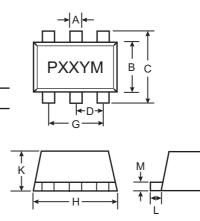
# PNP PRE-BIASED SMALL SIGNAL SOT-563 **DUAL SURFACE MOUNT TRANSISTOR**

### **Features**

- Epitaxial Planar Die Construction •
- Complementary NPN Types Available • (DDC)
- **Built-In Biasing Resistors** •
- Lead Free By Design/RoHS Compliant (Note 3) •

### **Mechanical Data**

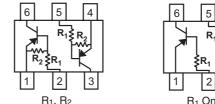
- Case: SOT-563 •
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram .
- Weight: 0.005 grams (approx.)

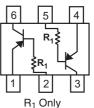


	SOT-563										
Dim	Min	Max	Тур								
Α	0.15	0.30	0.25								
В	1.10	1.25	1.20								
С	1.55 1.70 1.60										
D	0.50										
G	0.90	1.10	1.00								
н	1.50	1.70	1.60								
к	0.56	0.60	0.60								
L	0.15	0.25	0.20								
М	0.10	0.18	0.11								
All	Dimens	sions in	mm								



P/N	R1 (NOM)	R2 (NOM)	MARKING
DDA122LH	0.22KΩ	10KΩ	P81
DDA142JH	0.47KΩ	10KΩ	P82
DDA122TH	0.22KΩ	OPEN	P83
DDA142TH	0.47KΩ	OPEN	P84





SCHEMATIC DIAGRAM, TOP VIEW

#### Maximum Ratings @ $T_A = 25^{\circ}C$ unless otherwise specified

Characteristic		Symbol	Value	Unit		
Supply Voltage (6) to (1) and (3) to (4)	V <sub>CC</sub>	-50	V			
Input Voltage (2) to (1) and (5) to (4) DDA122LH DDA142JH		V <sub>IN</sub>	+5 to -6 +5 to -6	V		
Input Voltage (1) to (2) and (4) to (5) DDA122TH DDA142TH		V <sub>EBO (MAX)</sub>	-5	V		
Output Current All		Ι <sub>C</sub>	-100	mA		
Power Dissipation	Pd	150	mW			
Thermal Resistance, Junction to Ambient	R <sub>0JA</sub>	833	°C/W			
Operating and Storage and Temperature	Range	T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C		

1. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways). Notes:

2. Mounted on FR4 Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.

3. No purposefully added lead.



### **Electrical Characteristics** @ $T_A = 25^{\circ}C$ unless otherwise specified

R1, R2 Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Input Voltage	DDA122LH DDA142JH	V <sub>l(off)</sub>	-0.3 -0.3	_	_	V	$V_{CC}=-5V,\ I_O=-100\mu A$
	DDA122LH DDA142JH	V <sub>l(on)</sub>		_	-2.0 -2.0	V	$V_{O} = -0.3V$ , $I_{O} = -20mA$ $V_{O} = -0.3V$ , $I_{O} = -20mA$
Output Voltage		V <sub>O(on)</sub>		_	-0.3V	V	$I_0/I_1 = -5mA/-0.25mA$
Input Current DDA122LH DDA142JH		I		_	-28 -13	mA	V <sub>I</sub> = -5V
Output Current	Output Current			_	-0.5	μA	$V_{CC} = -50V, V_I = 0V$
DC Current Gain DDA122LH DDA142JH		Gı	56 56	_		_	$V_{O} = -5V, I_{O} = -10mA$
Gain-Bandwidth Product*		f⊤		200	—	MHz	$V_{CE} = -10V$ , $I_E = -5mA$ , f = 100MHz

\* Transistor - For Reference Only

<b>Electrical Characterist</b>	<b>ics</b> @ $T_A = 25^{\circ}C$	ied	R1-Only Types				
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltag	Collector-Base Breakdown Voltage				_	V	I <sub>C</sub> = -50μA
Collector-Emitter Breakdown Volta	Collector-Emitter Breakdown Voltage		-40		_	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage DDA122TH DDA142TH		BV <sub>EBO</sub>	-5		_	v	I <sub>E</sub> = -50μA I <sub>E</sub> = -50μA
Collector Cutoff Current		I <sub>CBO</sub>			-0.5	μA	V <sub>CB</sub> = -50V
Emitter Cutoff Current DDA122TH DDA142TH		I <sub>EBO</sub>			-0.5 -0.5	μA	V <sub>EB</sub> = -4V
Collector-Emitter Saturation Volta	ge	V <sub>CE(sat)</sub>			-0.3	V	$I_{\rm C}$ = -5mA, $I_{\rm B}$ = -0.25mA
DC Current Transfer Ratio DDA122TH DDA142TH		h <sub>FE</sub>	100 100	250 250	600 600	_	$I_C = -1mA$ , $V_{CE} = -5V$
Gain-Bandwidth Product*		f⊤		200	—	MHz	$V_{CE} = -10V$ , $I_E = 5mA$ , f = 100MHz

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## Ordering Information (Note 4)

Device	Packaging	Shipping
DDA122LH-7	SOT-563	3000/Tape & Reel
DDA142JH-7	SOT-563	3000/Tape & Reel
DDA122TH-7	SOT-563	3000/Tape & Reel
DDA142TH-7	SOT-563	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

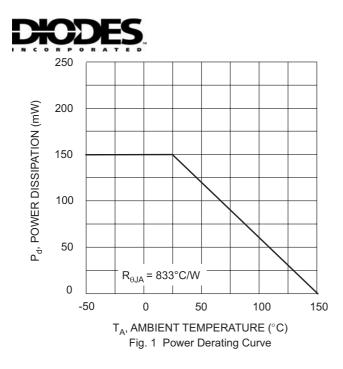
# **Marking Information**

PXXYM	

 $\begin{array}{l} XXX = Product Type \mbox{ Marking Code (See Page 1)} \\ YM = Date \mbox{ Code Marking } \\ Y = Year \mbox{ ex: } T = 2006 \\ M = Month \mbox{ ex: } 9 = September \end{array}$ 

Date Code Key

Year	20	02	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	٩	1	Р	R	S	Т	U	V	W	Х	Y	Z
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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